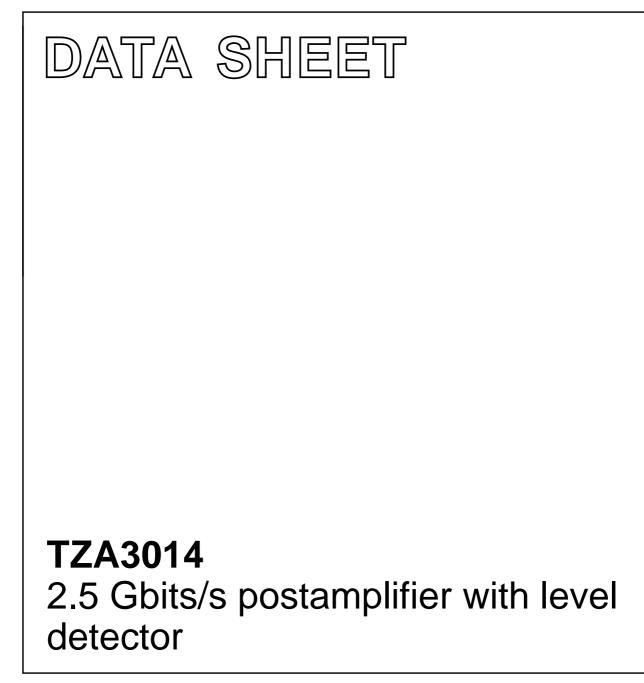
INTEGRATED CIRCUITS



Product specification Supersedes data of 2000 Aug 09 File under Integrated Circuits, IC19 2001 Jun 25



TZA3014

FEATURES

- Single 3.3 V power supply
- Wideband operation from 50 kHz to 2.5 GHz (typical value)
- Fully differential
- On-chip DC-offset compensation without external capacitor
- Interfacing with supplied positive or negative logic
- Positive Emitter Coupled Logic (PECL) or Current-Mode Logic (CML) compatible data outputs adjustable from 200 to 800 mV (p-p) single-ended
- Power-down capability for unused output or detector
- Rise and fall times of 80 ps (typical value)
- Inverted output possible
- Input level detection circuit for Received Signal Strength Indicator (RSSI) and Loss Of Signal (LOS), programmable from 0.4 to 400 mV (p-p) single-ended, with open-drain comparator output for directly interfacing positive or negative logic
- · Reference voltage for output level and LOS adjustment
- HTQFP32 and HBCC32 plastic packages with exposed pad
- Mute input.

ORDERING INFORMATION

APPLICATIONS

- Postamplifier for SDH/SONET transponder
- SDH/SONET wavelength converter
- PECL driver
- Fibre channel arbitrated loop
- Signal level detectors
- Swing converter CML 200 mV (p-p) to PECL 800 mV (p-p)
- 2.5 GHz clock amplification.

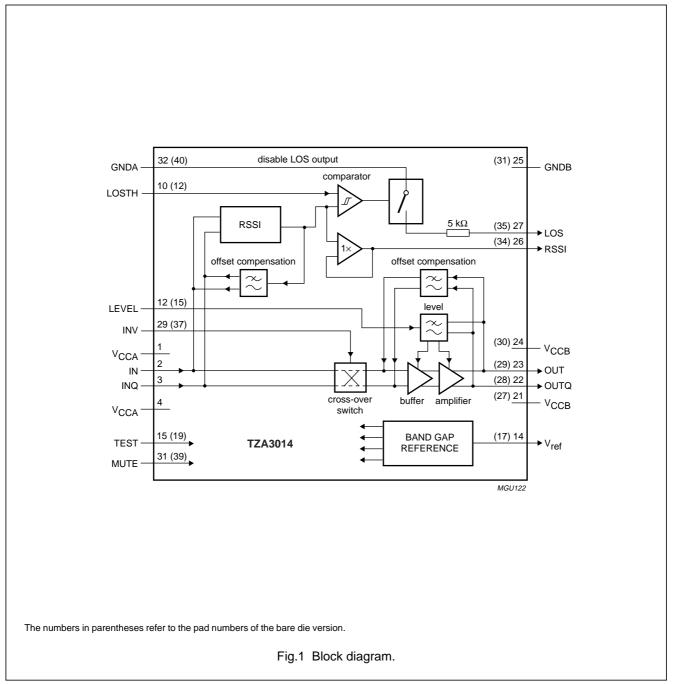
GENERAL DESCRIPTION

The TZA3014 is a low gain postamplifier with a LOS detector and a RSSI designed for use in critical signal path control applications, such as loop-through or Wavelength Division Multiplexing (WDM). The signal path is capable of operating from 50 kHz up to 2.5 GHz.

The TZA3014 can be delivered in HTQFP32 and HBCC32 packages and as bare die.

TYPE	PACKAGE				
NUMBER	NAME	DESCRIPTION	VERSION		
TZA3014HT	HTQFP32	plastic, heatsink thin quad flat package; 32 leads; body $5 \times 5 \times 1.0$ mm	SOT547-2		
TZA3014VH	HBCC32	plastic, heatsink bottom chip carrier; 32 terminals; body $5\times5\times0.65$ mm	SOT560-1		
TZA3014U	_	bare die; $2.22 \times 2.22 \times 0.28$ mm	_		

BLOCK DIAGRAM



TZA3014

PINNING

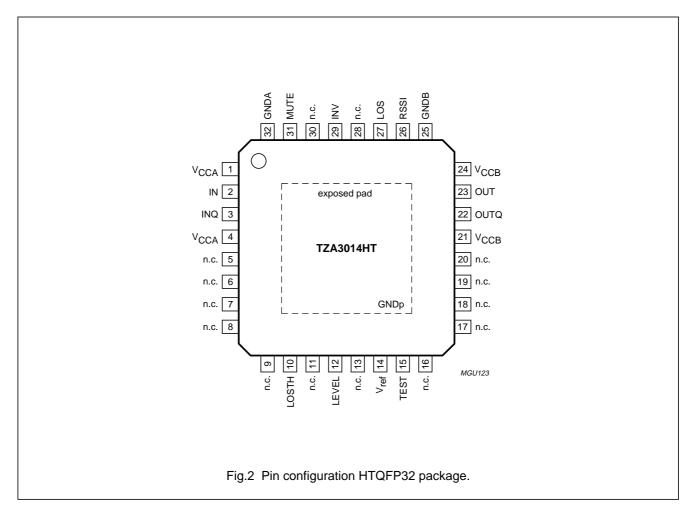
SYMBOL	PIN	PAD	TYPE ⁽¹⁾	DESCRIPTION
V _{CCA}	1	1	S	supply voltage for input and LOS detector
IN	2	2	I	differential input; complimentary to pin INQ; DC bias level is set internally at approximately V_{CC} – 0.33 V
INQ	3	3	I	differential input; complimentary to pin IN; DC bias level is set internally at approximately $V_{CC}-0.33~\text{V}$
V _{CCA}	4	4	S	supply voltage for input and LOS detector
n.c.	_	5	-	not connected
n.c.	-	6	-	not connected
n.c.	5	7	-	not connected
n.c.	6	8	I	not connected
n.c.	7	9	I	not connected
n.c.	8	10	S	not connected
n.c.	9	11	S	not connected
LOSTH	10	12	I	input for setting threshold level of LOS detector; threshold level is set by connecting external resistors between pins V_{CCA} and V_{ref} ; when forced to GNDA or not connected, the LOS detector is switched off
n.c.	11	13	I	not connected
n.c.	_	14	_	not connected
LEVEL	12	15	I	input for setting AC level of the output circuit; output signal level is set by connecting external resistors between pins V_{CCA} and V_{ref} ; when forced to V_{CCA} or not connected, pins OUT and OUTQ will be switched off
n.c.	13	16	I	not connected
V _{ref}	14	17	0	reference voltage for programming output level circuit and LOS threshold; typical value is V_{CC} – 1.6 V; no external capacitor allowed
n.c.	_	18	_	not connected
TEST	15	19	I	for test purposes only; to be left open-circuit in the application
n.c.	16	20	S	not connected
n.c.	17	21	S	not connected
n.c.	18	22	0	not connected
n.c.	19	23	0	not connected
n.c.	20	24	S	not connected
n.c.	_	25	_	not connected
n.c.	_	26	_	not connected
V _{CCB}	21	27	S	supply voltage for output circuit
OUTQ	22	28	0	PECL or CML compatible differential output; complimentary to pin OUT
OUT	23	29	0	PECL or CML compatible differential output; complimentary to pin OUTQ
V _{CCB}	24	30	S	supply voltage for output circuit
GNDB	25	31	S	ground for output circuit
n.c.	_	32	0	not connected
n.c.	_	33	O-DRN	not connected

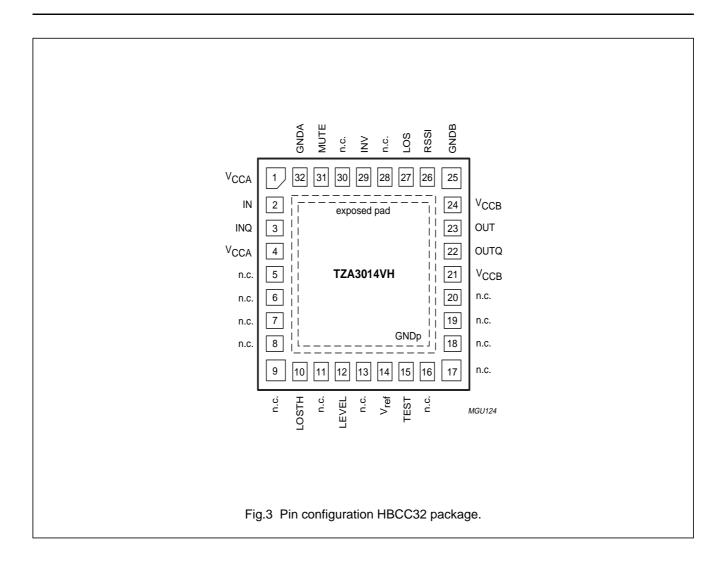
TZA3014

SYMBOL	PIN	PAD	TYPE ⁽¹⁾	DESCRIPTION
RSSI	26	34	0	RSSI output
LOS	27	35	O-DRN	output of LOS detector; direct drive to either positive or negative supplied logic via internal 5 $k\Omega$ resistor
n.c.	28	36	TTL	not connected
INV	29	37	TTL	input to invert the signal at pins OUT and OUTQ; supports positive or negative logic
n.c.	30	38	TTL	not connected
MUTE	31	39	TTL	input to mute the output signal on pins OUT ('0') and OUTQ ('1'); supports positive or negative logic
GNDA	32	40	S	ground for input and LOS detector
GNDp	pad	_	S	ground pad (exposed die pad)

Note

1. Pin type abbreviations: O = output, I = input, S = power supply, TTL = logic input and O-DRN = open-drain output.





FUNCTIONAL DESCRIPTION

The TZA3014 is a postamplifier with a RSSI circuit to provide output signals for RSSI and LOS (see Fig.1). The input signal can be amplified to a programmable level. An active level control circuit ensures this level. The control voltage on pin INV inverts the outputs, so avoiding a required complicated Printed Circuit Board (PCB) layout. An offset compensation circuit minimizes the effect of any voltage offset present at the input.

The RSSI and LOS detector are based on a 7-stage 'successive detection' circuit which provides a logarithmic output. The LOS detector is followed by a comparator with a programmable threshold. The input signal level detection is implemented to check if the input signal is above the user-programmed level. The user can ensure that data will only be transmitted when the input signal-to-noise ratio is sufficient for low bit error rate system operation. A second offset compensation circuit minimizes the effect of any voltage offset present in the logarithmic amplifier.

RF input circuit

The input circuit contains internal 50 Ω resistors decoupled to V_{CCA} via an internal common mode 12 pF capacitor (see Fig.4).

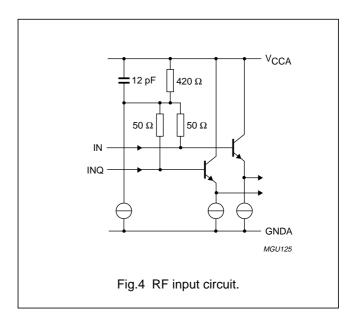
The inputs IN and INQ are DC-biased at approximately $V_{CCA} - 0.33$ V by an internal reference generator. The TZA3014 can be DC-coupled, but AC coupling is preferred. When DC-coupled, the drive source must operate within the allowable input range $(V_{CCA} - 1.0 \text{ V to } V_{CCA} + 0.3 \text{ V})$. The DC-offset voltage should stay below a few millivolts since the internal DC-offset compensation circuit has a limited correction range. When AC-coupled, do not use capacitors that cause a 3 dB cut-off point at 50 kHz (postamplifier cut-off point) or at 1 MHz (RSSI cut-off point).

RF output circuit

Matching the outputs of the postamplifier (see Fig.5) is not mandatory. In most applications, the receiving end of the transmission line will be properly matched, causing very few reflections.

Matching the transmitting end of the transmission line to absorb reflections only, is recommended for very sensitive applications.

In such cases, 100 Ω pull-up resistors should be connected to V_{CCB} and pins OUT and OUTQ as close as possible to the IC. However, for most applications these matching resistors are not required.



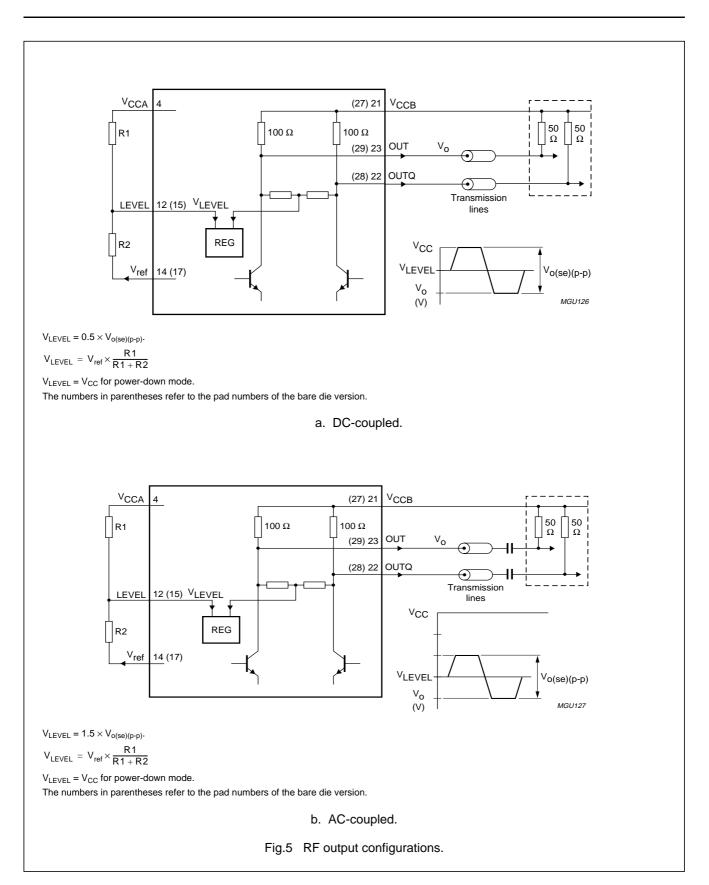
RF output level adjustment

The output level can be made compatible with CML or PECL by adjusting the voltage on pin LEVEL. The DC voltages on pins OUT and OUTQ relate to the DC voltage on pin LEVEL. Due to the effect of the 50 Ω load resistance at the receiving end, for a given peak-to-peak value on pins OUT and OUTQ, a different voltage is required on pin LEVEL in case the output is AC-coupled and when the output is DC-coupled (see Figs 5 and 6).

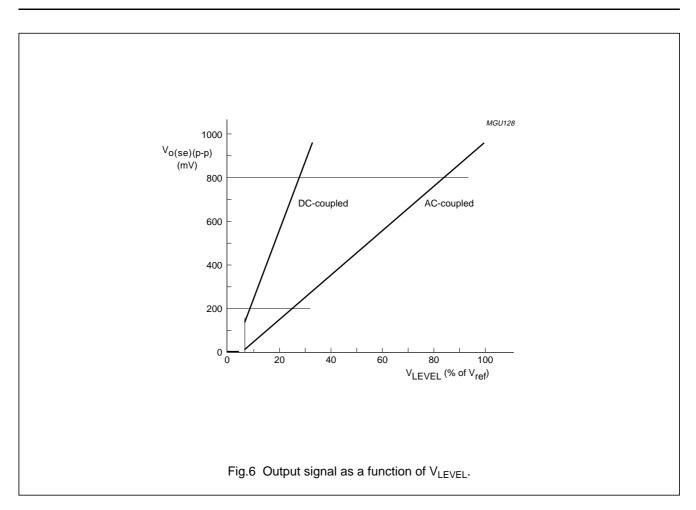
When pin LEVEL is not connected or connected to V_{CCA} , the postamplifier is in power-down state (see Fig.5).

DC-offset compensation loop

A DC-offset compensation loop connected between the amplifier output and the buffer input maintains the toggle point at the buffer input when there is no input signal (see Fig.1). This active control circuit is integrated and does not require an external capacitor. The loop time constant determines the lower cut-off frequency of the amplifier chain, and is internally fixed at approximately 5 kHz.



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TTL logic inputs MUTE and INV

It should be noted that switch control voltages in positive logic are inverted in case a negative supply voltage is used (see Fig.7).

Output signal as a function of inputs MUTE and INV

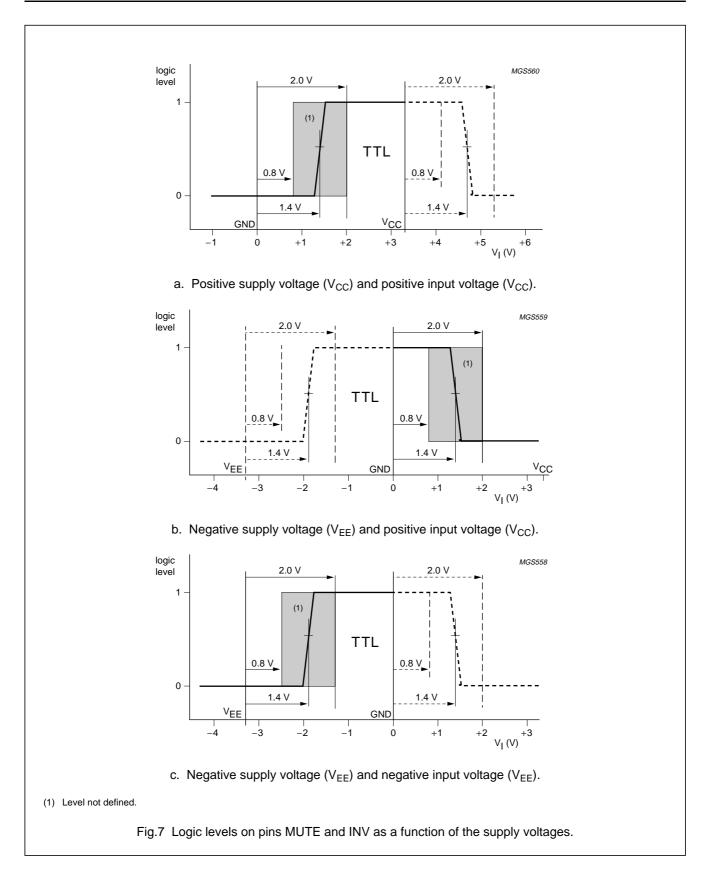
The default logic level for inputs MUTE and INV is 0 in case these pins are not connected. See Tables 1 and 2.

Table 1 OUT and OUTQ as a function of input MUTE

MUTE	OUT	ουτα
0	IN	INQ
1	'0'	'1'

Table 2 OUT and OUTQ as a function of input INV

INV	OUT	ουτα
0	IN	INQ
1	INQ	IN



RSSI and LOS detection

The TZA3014 monitors the level of the input AC signal. This function can prevent the output circuit from reacting to noise in case there is no valid input signal, and can ensure that only data is transmitted when there is sufficient input signal for low bit error rate system operation.

The RSSI uses seven limiting amplifiers in a 'successive detection' topology to closely approximate a logarithmic response over a total range of 70 dB. The AC signal is full-wave rectified by a detector at each amplifier stage. Each detector output has a current driver followed by a low-pass filter providing the first stage in the recovery of the average value of the demodulated input signal. The total current from each detector output is converted to a voltage by an internal load resistor and then buffered. When the RSSI output is used, input pin LOSTH is not to be connected to GND (standby mode). The RSSI output follows the internal 3 dB hysteresis of the LOS comparator. The LOS comparator detects when the input signal level rises above a programmable fixed threshold. Then pin LOS gets a LOW-level. The threshold level is determined by the voltage on pin LOSTH and by the level of the input AC signal (see Fig.8). A filter with a nominal time constant of 1 µs prevents noise spikes from triggering the level detector.

The LOS comparator has an internal 3 dB hysteresis and drives an open-drain circuit with a 5 k Ω internal resistor allowing it to directly interface positive or negative logic circuits (see Fig.9).

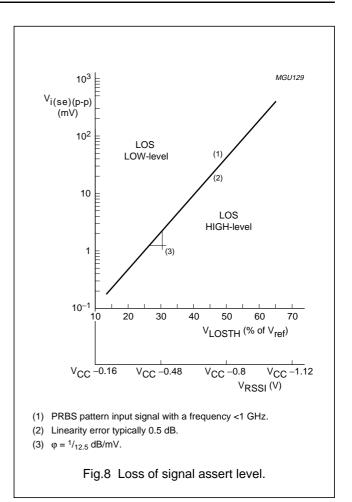
Its response is independent of the input signal polarity due to the circuit design and to the demodulating action of the detector which transforms the alternating input voltage to a rectified and filtered quasi DC output signal. The logarithmic voltage slope of the TZA3014 is $\varphi = 1/_{12.5}$ dB/mV and mostly is independent of temperature and supply voltage due to four feedback loops in the reference circuit. The LOS detector output voltage is derived from V_{ref}.

The sensitivity of the LOS detector is affected by the RMS value of the input signal which, in its turn, depends on the frequency.

V_{LOSTH} can be calculated using the following formula:

$$V_{CC} + 0.458 - S_{RSSI} \times 20 \log \left(\frac{V_{i(p-p)}}{26E - 8} \right)$$
 (1)

where S_{RSSI} in [mV/dB]; V_{LOSTH} , V_{RSSI} and $V_{i(p-p)}$ in [V].



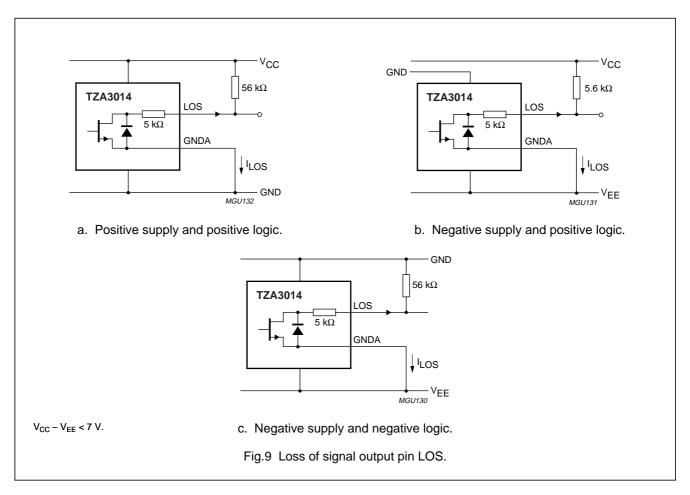
Example: a 200 mV (p-p) single-ended 1.2 GB/s PRBS input signal will have a V_{RSSI} voltage of V_{CC} – 1.013 V.

If the offset voltage of the first stage increases above a certain level, the high DC gain of the amplifier circuit will cause successive stages to limit prematurely. This is prevented by the LOS detector offset control loop which extends the lower end of the amplifier's dynamic range. The offset is automatically and continuously compensated by a feedback path from the last stage. An offset at the output of the logarithmic converter is equivalent to a change of amplitude at the input.

Using DC-coupling, with signal absence, and V_{IN} not equal to V_{INQ} (mute), the LOS detector detects full signal. Only very small signals with an average value equal to zero, can result into a zero output.

 $V_{IOSTH} = V_{RSSI} =$

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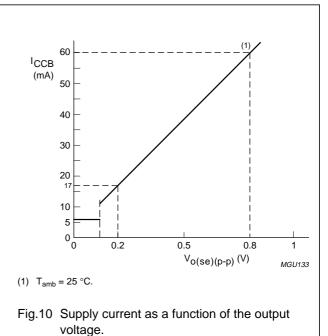
Supply current

For the supply current I_{CCB} , see Fig.10.

Using a positive supply voltage

Although the TZA3014 has been designed to use a single +3.3 V supply voltage (see Fig.11), some care should be taken with respect to RF transmission lines. The on-chip signals refer to the various V_{CC} pins. The external transmission lines will most likely be referred to the pins GNDA and GNDB, being the system ground.

The RF signals will change from one reference plane to another when interfacing the RF inputs and outputs. A positive supply application is very vulnerable to interference with respect to this point. For a successful +3.3 V application, special care should be taken when designing the PCB layout in order to reduce the influence of interference and to keep the positive supply voltage as clean as possible.



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{CC}	supply voltage	-0.5	+5.5	V
V _n	DC voltage			
	pins IN, INQ, LOSTH, LEVEL, V_{ref} , TEST, OUTQ, OUT, GNDp, V_{CCA} and V_{CCB}	-0.5	V _{CC} + 0.5	V
	pins LOS, INV and MUTE	-0.5	+7	V
l _n	DC current			
	pins IN and INQ	-20	+20	mA
	pins LOSTH and LEVEL	0	14	μA
	pins V _{ref} , TEST and LOS	-1	+1	mA
	pins OUT and OUTQ	-30	+30	mA
	pins INV and MUTE	0	20	μA
P _{tot}	total power dissipation	_	0.6	W
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	-	150	°C
T _{amb}	ambient temperature	-40	+85	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-s)}	thermal resistance from junction to solder point (exposed die pad)	note 1	15	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	1s2p multi-layer test board; notes 1 and 2	33	K/W
R _{th(s-a)}	thermal resistance from solder point to ambient (exposed die pad)	1s2p multi-layer test board; notes 1 and 2	18	K/W
R _{th(s-a)(req)}	required thermal resistance from	LOS detector switched on		
	solder point to ambient	$V_o = 200 \text{ mV} (p-p) \text{ single-ended}$	130	K/W
		$V_o = 800 \text{ mV} (p-p) \text{ single-ended}$	75	K/W

Notes

1. JEDEC standard.

2. HTQFP32 and HBCC32 packages.

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CHARACTERISTICS

Typical values at $T_{amb} = 25 \text{ °C}$ and $V_{CC} = 3.3 \text{ V}$; minimum and maximum values are valid over the entire ambient temperature range and supply voltage range; all voltages referenced to ground; note 1; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply (pi	ns V _{CCA} and V _{CCB})		I	1		
V _{CC}	supply voltage		3.13	3.3	3.47	V
I _{CCA}	supply current A	LOS detector power-down	14	24	34	mA
		LOS detector switched on	24	40	56	mA
I _{CCB}	supply current B	amplifier power-down	2	6	10	mA
		V _o = 200 mV (p-p) single-ended	11	17	24	mA
		V _o = 800 mV (p-p) single-ended	43	60	77	mA
P _{tot}	total power dissipation	power-down	60	100	240	mW
		V _o = 200 mV (p-p) single-ended	120	190	270	mW
		V _o = 800 mV (p-p) single-ended	250	330	450	mW
ТС	temperature coefficient	LOS detector switched on;	-80	-50	-30	μΑ/Κ
		$V_o = 800 \text{ mV} (p-p)$ single-ended; I_{CCB}	-50	-30	-15	μΑ/Κ
Tj	junction temperature		-40	-	+125	°C
T _{amb}	ambient temperature		-40	+25	+85	°C
RF inputs i	in general (PECL or CML ir	put pins IN and INQ)	•	•	•	•
V _{I(bias)}	DC input bias voltage		$V_{CC} - 0.4$	V _{CC} - 0.33	V _{CC} - 0.28	V
VI	DC and AC input window voltage	note 2	V _{CC} – 1.0	-	V _{CC} + 0.3	V
R _i	input resistance	single-ended	35	50	70	Ω
Ci	input capacitance	single-ended; note 2	0.6	0.8	1.2	pF
Cross-over	switch and postamplifier					
PECL OR C	ML INPUT PINS IN AND INQ					
V _{i(p-p)}	input voltage swing (peak-to-peak value)	single-ended; notes 2 and 3	50	-	500	mV
$\alpha_{OS(red)}$	input offset reduction	V _o = 200 mV (p-p) single-ended; note 4	3.8	9	13.5	dB
		V _o = 800 mV (p-p) single-ended; note 4	6	14	22	dB
V _{io(cor)}	input offset voltage correction range (peak-to-peak value)	single-ended	-10	-	+10	mV
V _{n(i)(eq)(rms)}	equivalent input noise voltage (RMS value)	V _o = 800 mV (p-p) single-ended; note 2	-	75	170	μV
Fn	noise factor	note 2	-	5	12	dB

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BUFFER AND) AMPLIFIER	1		1		
G _v	small signal voltage gain	V _o = 200 mV (p-p) single-ended; note 5	9	15	20	dB
		V _o = 800 mV (p-p) single-ended; note 5	21	29	34	dB
f _D	signal path data rate	notes 6 and 7	_	2.5	-	Gbits/s
f _{-3dB(I)}	low –3 dB cut-off frequency DC compensation	note 2	2	5	10	kHz
f _{-3dB(h)}	high –3 dB cut-off frequency		-	2.0	-	GHz
t _{PD}	propagation delay	note 2	150	200	250	ps
Δt_{PD}	propagation delay difference	at the same signal levels; note 2	-	0	5	ps
J	total jitter	20 bits of the 28.5 kbits pattern; notes 2 and 8	-	8	-	ps
α_{ct}	crosstalk	note 9	_	110	-	dB
PECL OR C	ML OUTPUTS (PINS OUT AND	OUTQ)				
V _{o(se)(p-p)}	single-ended output voltage (peak-to-peak value)	50 Ω load	200	_	800	mV
TC _{Vo}	temperature coefficient output voltage		-1	0	+1	mV/K
t _r	rise time	20% to 80%; notes 6 and 8	_	80	_	ps
t _f	fall time	80% to 20%; notes 6 and 8	_	80	-	ps
R _o	output resistance	single-ended	70	100	130	Ω
Co	output capacitance	single-ended; note 2	0.6	0.8	1.2	pF
LEVEL CONT	ROL INPUT (PIN LEVEL)					
Vi	input voltage		$V_{CC} - V_{ref}$	_	V _{CC}	V
R _i	input resistance	referenced to V _{CC}	200	350	600	kΩ
SWITCH CIR	CUIT					-
t _a	assert time	multiplexer and inverter	_	100	_	ns
t _d	de-assert time	multiplexer and inverter	-	80	-	ns
	PINS MUTE AND INV					
V _{IL}	LOW-level input voltage	positive logic; note 10	-0.3	_	+0.8	V
V _{IH}	HIGH-level input voltage	positive logic; note 10	2	-	V _{CC} + 0.8	V
R _i	input resistance	referenced to GNDA	100	180	400	kΩ
li	input current		-40	-	+40	μA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
RSSI and L	OS detector		-1			
PECL OR C	ML INPUT PINS IN AND INQ					
V _{i(p-p)}	input voltage swing (peak-to-peak value)	single-ended	0.4	-	400	mV
$\alpha_{OS(red)}$	input offset reduction	notes 2 and 4	25	40	50	dB
V _{io(cor)}	on-chip DC-offset compensation correction range	peak-to-peak value; single-ended	-5	_	+5	mV
RSSI CIRCU	ИТ					
f _{-3dB(l)}	low –3 dB cut-off frequency		0.5	1	2	MHz
f _{-3dB(h)}	high –3 dB cut-off frequency	note 11	1.5	2	2.5	GHz
DR	dynamic range		57	60	63	dB
S _{RSSI}	RSSI sensitivity	50 MHz, square; note 11	10	12.5	15	mV/dB
		620 MHz, square; note 11	10	12	14	mV/dB
		1.2 GHz, square; note 11	9	11	13.5	mV/dB
		100 MB/s PRBS (2 ³¹ – 1); note 11	9	12.5	15	mV/dB
		1.2 GB/s PRBS (2 ³¹ – 1); note 11	10	12	14.5	mV/dB
		2.4 GB/s PRBS (2 ³¹ – 1); note 11	10	12	14	mV/dB
TC _{sens}	temperature coefficient sensitivity		-2	0	+2	μV/dBK
LE	linearity error	see Fig.8; note 2	_	0.5	1	dB
LOS DETEC	TOR					
hys _{LOS}	LOS hysteresis	input signal waveform dependent	2.0	3.0	4.0	dB
ta	assert time	note 2	_	-	5	μs
t _d	de-assert time	note 2	_	-	5	μs
INPUT PIN L	OSTH					
Vi	input voltage		0	_	V _{CC}	V
R _i	input resistance	referenced to GNDA	150	350	600	kΩ
OUTPUT PIN	LOS					1
I _{o(sink)}	output sink current		_	_	1	mA
R _o	output resistance	internal output series resistance	3.5	5	6.5	kΩ

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
OUTPUT PIN	N RSSI				ł	
Vo	output voltage		V _{CC} – 1.2	-	V _{CC}	V
lo	output current		-1	_	+1	mA
Band gap	reference circuit					
OUTPUT PIN	v V _{ref}					
V _{ref}	reference voltage		V _{CC} - 1.85	V _{CC} – 1.6	V _{CC} - 1.45	V
C _{ext}	allowed external capacitance		-	-	10	pF
I _{o(sink)}	output sink current		_	_	500	μA

Notes

1. It is assumed that both CML inputs carry a complementary signal with the specified peak-to-peak value (true differential excitation).

- 2. Guaranteed by design.
- 3. Minimum signal with limiting output.

4.
$$\alpha_{OS(red)} = \frac{G_{AC}}{G_{DC}}$$

5.
$$G_V = \frac{V_o}{V_i}$$

- 6. Based on -3 dB cut-off frequency and rise/fall time.
- 7. Low limit can go as low as DC if the input signal overrides the input offset voltage correction range.
- 8. $V_i = 100 \text{ mV} (p-p)$ single-ended, $V_o = 800 \text{ mV} (p-p)$ single-ended.
- 9. Crosstalk of IC only.
- 10. When using a negative supply voltage, positive or negative logic can be used. The values will be different, see Fig.7.
- 11. Sensitivity depends on the waveform and is therefore a function of –3 dB cut-off frequency; see Section "RSSI and LOS detection", Equation (1).

APPLICATION INFORMATION

RF input and output connections

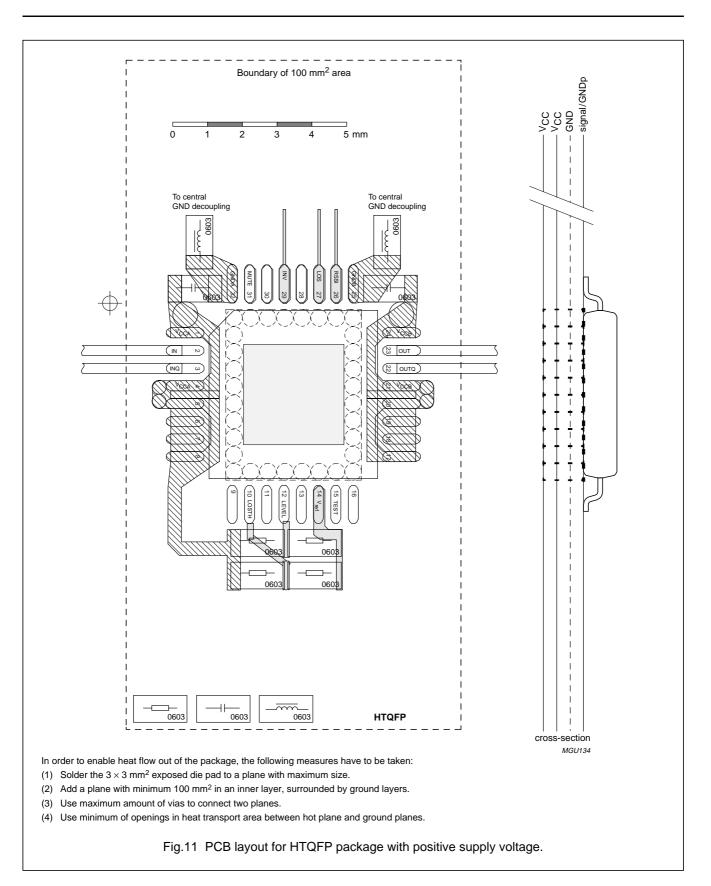
Striplines, or microstrips, with an odd mode characteristic impedance of $Z_0 = 50 \ \Omega$ have to be used for the differential RF connections on the PCB. This applies to both signal inputs and signal outputs. Each pair of lines should have the same length.

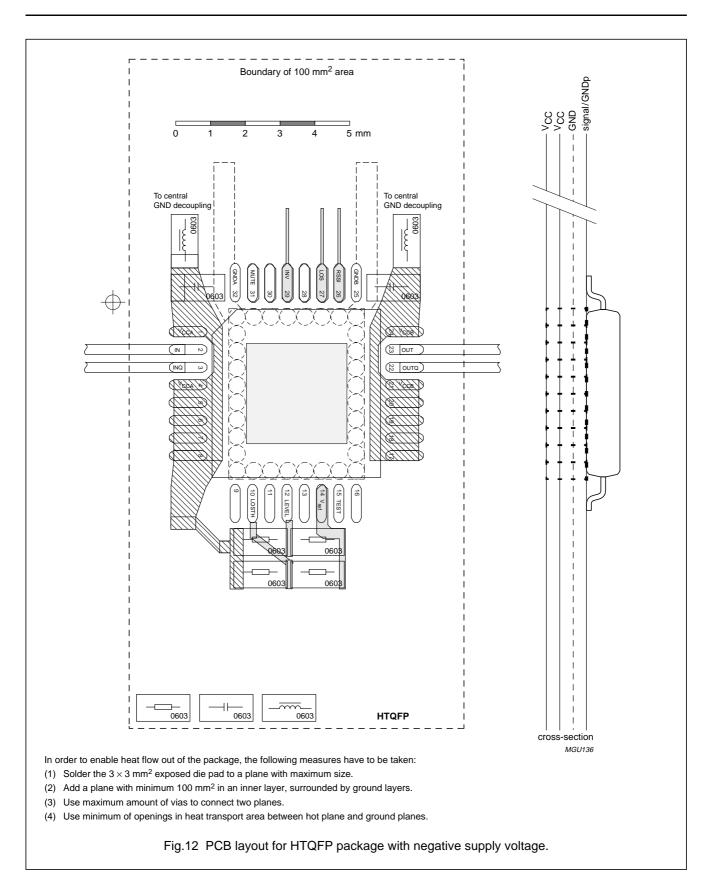
Grounding and power supply decoupling

The PCB ground connection has to be a large area of copper connected to a common ground plane with an inductance as low as possible.

To minimize low frequency switching noise in the vicinity of the TZA3014, the power supply line should be filtered once using a beaded capacitor circuit having a low cut-off frequency.

The exposed die pad GNDp connection on the PCB must be a large area of copper to aid the transfer of heat from the IC to the PCB (see Figs 11 and 12).





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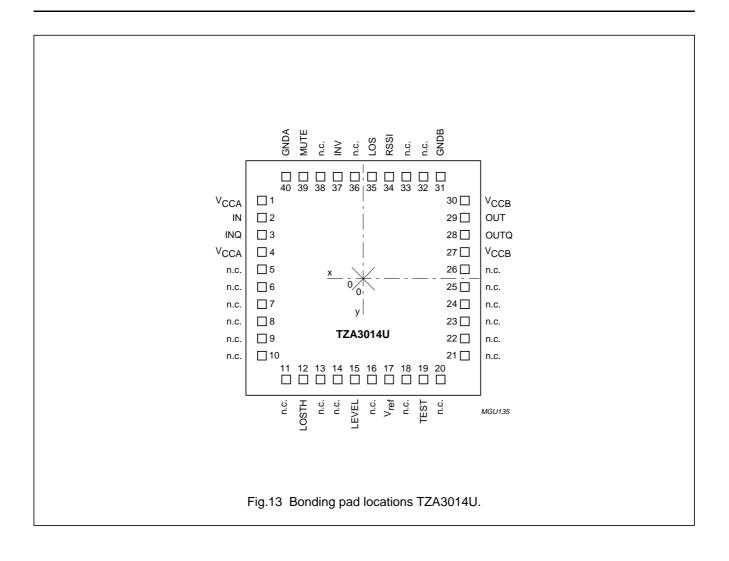
BONDING PAD INFORMATION

SYMBOL	DAD	COORD	INATES ⁽¹⁾
STMBOL	PAD	x	у
V _{CCA}	1	-928	+710
IN	2	-928	+553
INQ	3	-928	+396
V _{CCA}	4	-928	+239
n.c.	5	-928	+81
n.c.	6	-928	-81
n.c.	7	-928	-239
n.c.	8	-928	-396
n.c.	9	-928	-553
n.c.	10	-928	-710
n.c.	11	-707	-928
LOSTH	12	-550	-928
n.c.	13	-393	-928
n.c.	14	-236	-928
LEVEL	15	-79	-928
n.c.	16	+79	-928
V _{ref}	17	+236	-928
n.c.	18	+393	-928
TEST	19	+550	-928
n.c.	20	+707	-928
n.c.	21	+928	-710
n.c.	22	+928	-553
n.c.	23	+928	-396
n.c.	24	+928	-239

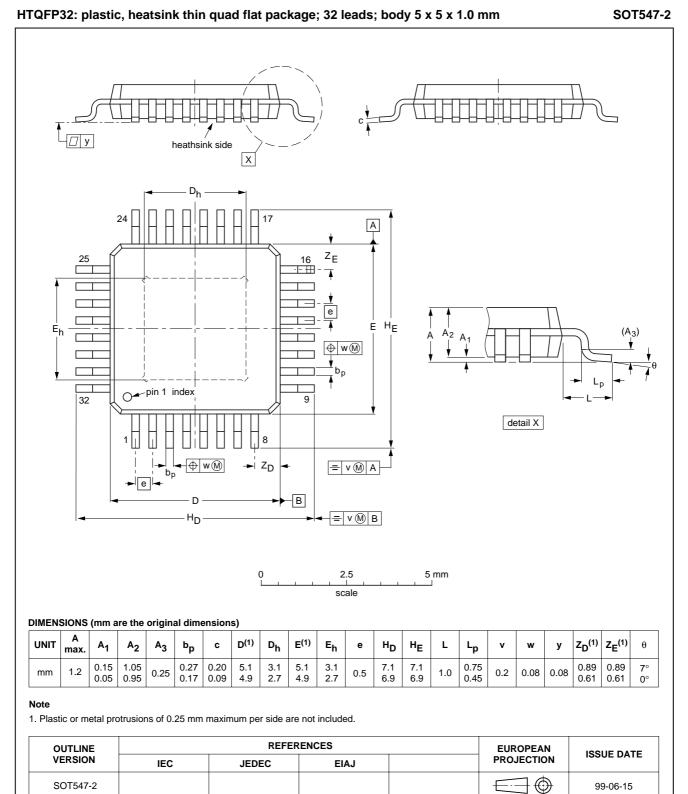
SYMBOL	PAD	COORDINATES ⁽¹⁾	
		x	У
n.c.	25	+928	-81
n.c.	26	+928	+81
V _{CCB}	27	+928	+239
OUTQ	28	+928	+396
OUT	29	+928	+553
V _{CCB}	30	+928	+710
GNDB	31	+707	+928
n.c.	32	+550	+928
n.c.	33	+393	+928
RSSI	34	+236	+928
LOS	35	+79	+928
n.c.	36	-79	+928
INV	37	-236	+928
n.c.	38	-393	+928
MUTE	39	-550	+928
GNDA	40	-707	+928

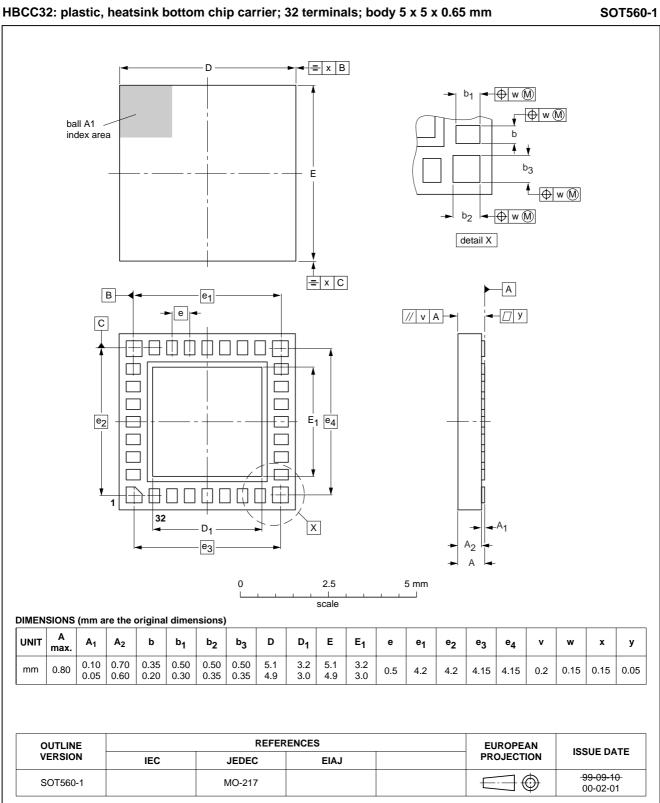
Note

All x and y coordinates represent the position of the centre of the pad in μm with respect to the centre of the die (see Fig.13).



PACKAGE OUTLINES





SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ\text{C}.$

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
FACKAGE	WAVE	REFLOW ⁽¹⁾
BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable ⁽²⁾	suitable
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS	
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